NPA2040-MQ



27.5 – 31 GHz GaN 8 W Power Amplifier

Product Description

The Nxbeam NPA2040-MQ is a Ka-band high power amplifier fabricated in 0.2um GaN HEMT on SiC in a metal QFN package. The amplifier operates from 27.5 to 31 GHz and provides an average of 8 W saturated output power, 25% PAE, and 22 dB of linear gain. The metal QFN is designed for easy system integration with RF input and output ports matched to 50 ohms.



Applications

- Ka-band Satellite Communications
- 5G Infrastructure
- Point-to-Point/Multipoint Digital Radios

Key Features

Frequency: 27.5 – 31 GHz
Linear Gain (Ave.): 22 dB

Psat (Ave.): 8 WPAE (Ave.): 25%

Electrical Specifications

Test Condition: Vd = 27 V, Idq = 0.5 A, CW Performance, Typical Performance at 25°C

| Parameter | | Min | Typical | Max | Unit |
|--------------------------------------|----------|------|---------|-----|------|
| Frequency | | 27.5 | | 31 | GHz |
| Gain (Small Signal) | 27.5 GHz | | 20.8 | | |
| | 29 GHz | | 22.5 | | dB |
| | 31 GHz | | 23.0 | | |
| | 27.5 GHz | | 38.2 | | |
| Output Power (at Psat, Pin=23.3 dBm) | 29 GHz | | 39.6 | | dBm |
| | 31 GHz | | 38.3 | | |
| | 27.5 GHz | | 22.0 | | |
| PAE (at Psat, Pin=23.3 dBm) | 29 GHz | | 28.0 | | % |
| | 31 GHz | | 27.0 | | |
| | 27.5 GHz | | 15.2 | | |
| Power Gain (at Psat, Pin=23.3 dBm) | 29 GHz | | 15.6 | | dB |
| | 31 GHz | | 16.8 | | |
| | 27.5 GHz | | 6 | | |
| Input Return Loss | 29 GHz | | 25 | | dB |
| | 31 GHz | | 14 | | |
| | 27.5 GHz | | 8 | | |
| Output Return Loss | 29 GHz | | 12 | | dB |
| | 31 GHz | | 14 | | |

Maximum Quiescent Bias

| Parameter | Max | Unit |
|-------------------------------|-----|------|
| Drain Voltage (Vd1, Vd2, Vd3) | 28 | V |
| Drain Current (Id1) | 140 | mA |
| Drain Current (Id2) | 160 | mA |
| Drain Current (Id3) | 550 | mA |

Maximum quiescent bias represents the operational bias used during reliability life testing. Biasing the part at or below this bias ensures reliability will be bound by the published reliability results.

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Absolute Maximum Ratings (Temp. = 25°C)

| Parameter | Min | Max | Unit |
|-------------------------------|-----|------|------|
| Drain Voltage (Vd1, Vd2, Vd3) | | 28 | V |
| Drain Current (Id1) | | 350 | mA |
| Drain Current (Id2) | | 400 | mA |
| Drain Current (Id3) | | 1400 | mA |
| Gate Voltage (Vg1, Vg2, Vg3) | -8 | 0 | V |

Absolute maximum ratings represent the maximum current under power saturation conditions.

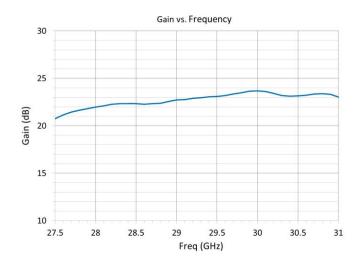
Recommended Quiescent Operating Condition

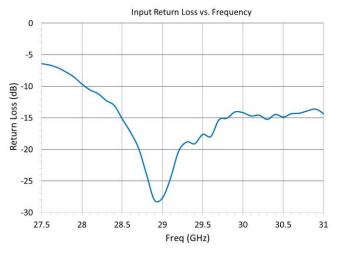
| Parameter | Value | Unit |
|-----------------------------------|--------------|------|
| Drain Voltage (Vd) | 20 - 27 | > |
| Drain Current (Id1) | up to 140 | mA |
| Drain Current (Id2) | up to 160 | mA |
| Drain Current (Id3) | up to 550 | mA |
| Gate Voltage (Vg) (Typical Range) | -5.5 to -3.5 | ٧ |

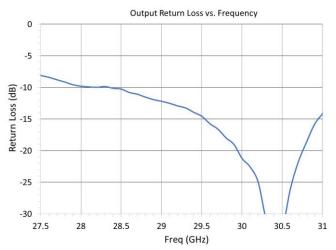
Gate voltage will vary based on desired current per stage

Small Signal Performance

Test Condition: Vd = 27 V, Idq = 0.5 A, (CW Performance, Typical Performance at 25°C)







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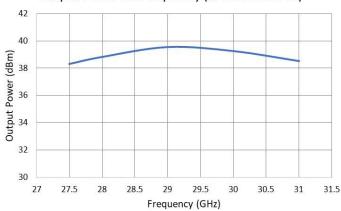
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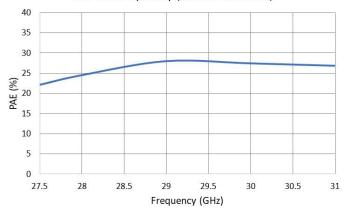
Large Signal Performance

Test Condition: Vd = 27 V, Idq = 0.5 A, Pin = 23.3 dBm (Psat) (CW Performance, Typical Performance at 25°C)

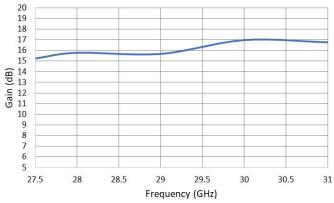
Output Power vs. Frequency (at 23.3 dBm Pin)



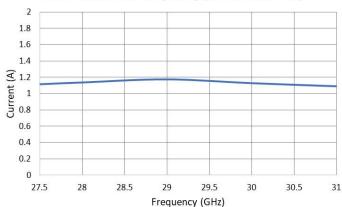
PAE vs. Frequency (at 23.3 dBm Pin)



Gain vs. Frequency (at 23.3 dBm Pin)



Drain Current vs. Frequency (at 23.3 dBm Pin)



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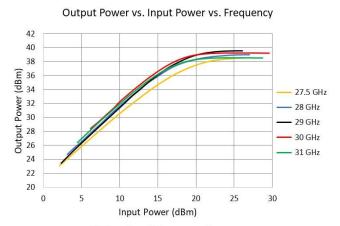


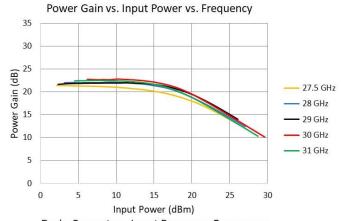


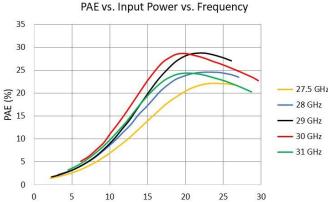


Large Signal Performance

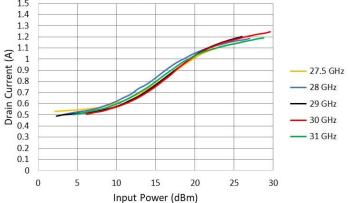
Test Condition: Vd = 27 V, Idq = 0.5 A, (CW Performance, Typical Performance at 25°C)







Drain Current vs. Input Power vs. Frequency



2-Tone Linearity Performance

Input Power (dBm)

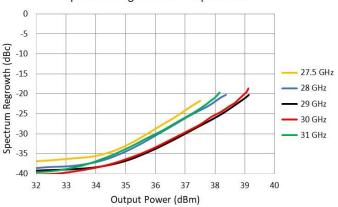
Test Condition: Vd = 27 V, Idq = 0.5 A 10 MHz Tone Spacing



Spectral Regrowth Performance

Test Condition: Vd = 27 V, Idq = 0.5 A QPSK, 10 MSPS, Alpha = 0.2

Spectrum Regrowth vs. Output Power



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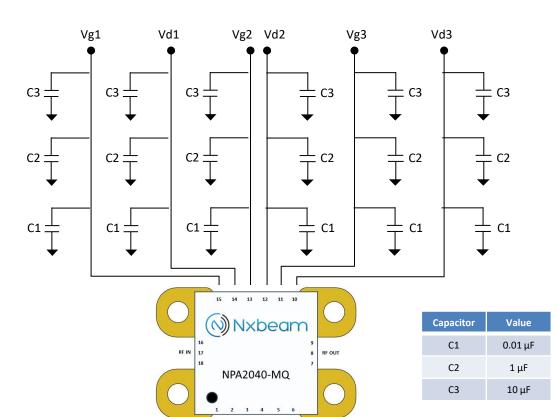


Connection and Off-Chip Components

The following diagram shows the recommended off-chip components. The off-chip components should be located as close to the part as possible. Please consult with Nxbeam on other off-chip network variations.

| Pad Num. | Function |
|----------|----------|
| 1 | NC |
| 2 | NC |
| 3 | NC |
| 4 | NC |
| 5 | NC |
| 6 | NC |
| 7 | GND |
| 8 | RF OUT |
| 9 | GND |

| Pad Num. | Function |
|----------|----------|
| 10 | Vd3 |
| 11 | Vg3 |
| 12 | Vd2 |
| 13 | Vg2 |
| 14 | Vd1 |
| 15 | Vg1 |
| 16 | GND |
| 17 | RF IN |
| 18 | GND |



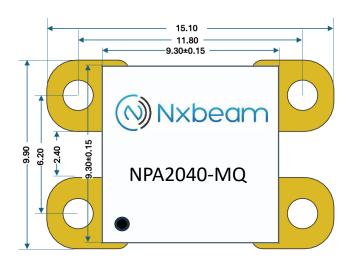
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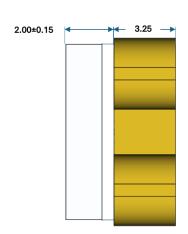


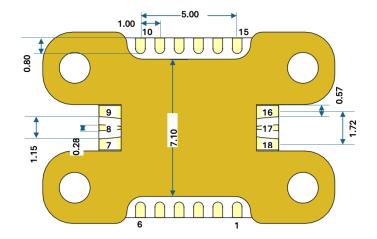




Dimensions (all dimensions in mm)







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Bias Information

Bias-up Procedure:

- 1.) It is recommended that voltage and current limits are set on the voltage supply's prior to biasing the product.
- 2.) Ensure power supplies are properly grounded to the product test fixture.
- 3.) Apply a negative gate voltage of -7V to Vg1, Vg2, and Vg3 to ensure all devices are pinched off.
- 4.) Gradually increase the drain bias voltage (Vd1, Vd2, Vd3) to the desired bias level but not to exceed the maximum voltage of 28 V.
- 5.) Gradually increase the gate voltages (Vg1, Vg2, Vg3) while monitoring the drain current until the desired drain current in each stage is achieved.
- 6.) Apply RF signal.

Bias-down Procedure:

- 1.) Turn off RF signal.
- 2.) Gradually decrease Vg1, Vg2, and Vg3 down to -7 V.
- 3.) Gradually decrease the drain voltages (Vd1, Vd2, Vd3) down to 0 V.
- 4.) Gradually increase gate voltages (Vg1, Vg2, Vg3) to 0 V.
- 5.) Turn off supply voltages

ESD Sensitive Product



Important Information

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